

Switch-mode Power Rectifiers

MBR2045EMFS, NRVB2045EMFS

These state-of-the-art devices have the following features:

Features

- Low Power Loss / High Efficiency
- New Package Provides Capability of Inspection and Probe After Board Mounting
- Guardring for Stress Protection
- Low Forward Voltage Drop
- 150°C Operating Junction Temperature
- Wettable Flacks Option Available
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free and Halide-Free Devices

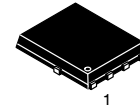
Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements

Applications

- Excellent Alternative to DPAK in Space-Constrained Automotive Applications
- Output Rectification in Compact Portable Consumer Applications
- Freewheeling Diode used with Inductive Loads

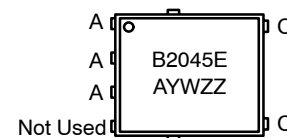
SCHOTTKY BARRIER RECTIFIERS 20 AMPERES 45 VOLTS



SO-8 FLAT LEAD
CASE 488AA
STYLE 2



MARKING DIAGRAM



B2045E = Specific Device Code
 A = Assembly Location
 Y = Year
 W = Work Week
 ZZ = Lot Traceability

ORDERING INFORMATION

Device	Package	Shipping†
NRVB2045EMFST1G	SO-8 FL (Pb-Free)	1,500 / Tape & Reel
NRVB2045EMFST3G	SO-8 FL (Pb-Free)	5,000 / Tape & Reel

DISCONTINUED (Note 1)

MBR2045EMFST1G	SO-8 FL (Pb-Free)	1,500 / Tape & Reel
MBR2045EMFST3G	SO-8 FL (Pb-Free)	5,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, [BRD8011/D](#).

1. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

MBR2045EMFS, NRVB2045EMFS

MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V _{RRM} V _{RWM} V _R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	45	V
I _{F(AV)}	Average Rectified Forward Current (Rated V _R , T _C = 130°C)	20	A
I _{FRM}	Peak Repetitive Forward Current, (Rated V _R , Square Wave, 20 kHz, T _C = 120°C)	40	A
I _{FSM}	Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	400	A
T _{stg}	Storage Temperature Range	-65 to +175	°C
T _J	Operating Junction Temperature	-55 to +150	°C
E _{AS}	Unclamped Inductive Switching Energy (10 mH Inductor, Non-repetitive)	150	mJ
	ESD Rating (Human Body Model)	3B	
	ESD Rating (Machine Model)	M4	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

NOTE: The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dPD/dT_J < 1/R_{JA}$

THERMAL CHARACTERISTICS

Symbol	Characteristic	Typ	Max	Unit
R _{θJC}	Thermal Resistance, Junction-to-Case, Steady State (Assumes 600 mm ² 1 oz. copper bond pad, on a FR4 board)	-	1.6	°C/W

ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Typ	Max	Unit
V _F	Instantaneous Forward Voltage (Note 1) (i _F = 10 A, T _J = 125°C) (i _F = 10 A, T _J = 25°C) (i _F = 20 A, T _J = 125°C) (i _F = 20 A, T _J = 25°C)	0.35 0.45 0.43 0.51	0.47 0.56 0.58 0.64	V
i _R	Instantaneous Reverse Current (Note 1) (Rated dc Voltage, T _J = 125°C) (Rated dc Voltage, T _J = 25°C)	48 0.09	100 0.40	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

TYPICAL CHARACTERISTICS

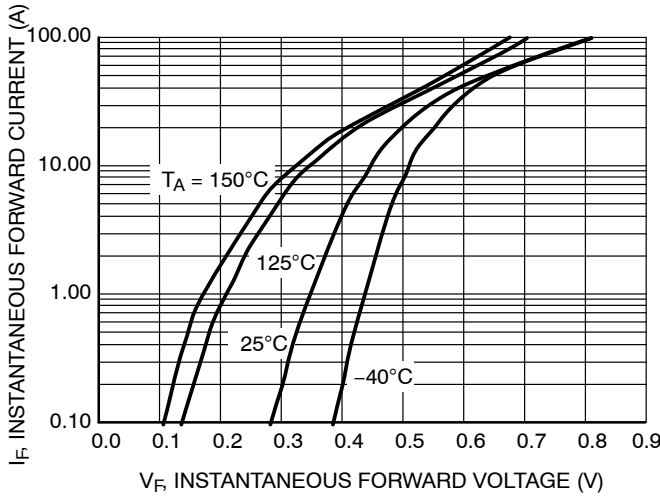


Figure 1. Typical Instantaneous Forward Voltage

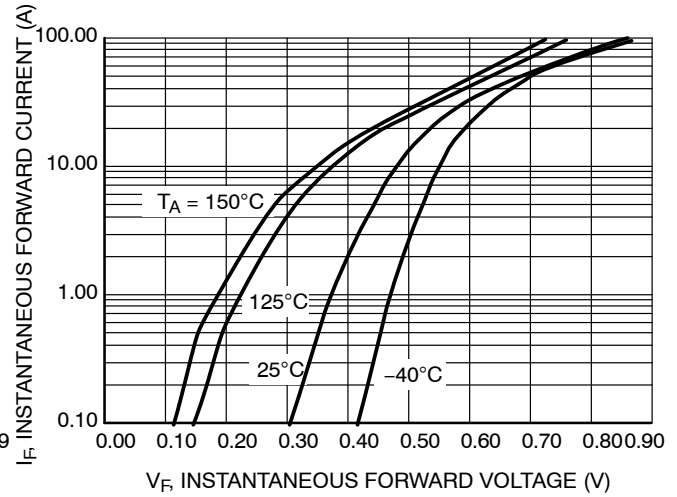


Figure 2. Maximum Instantaneous Forward Voltage

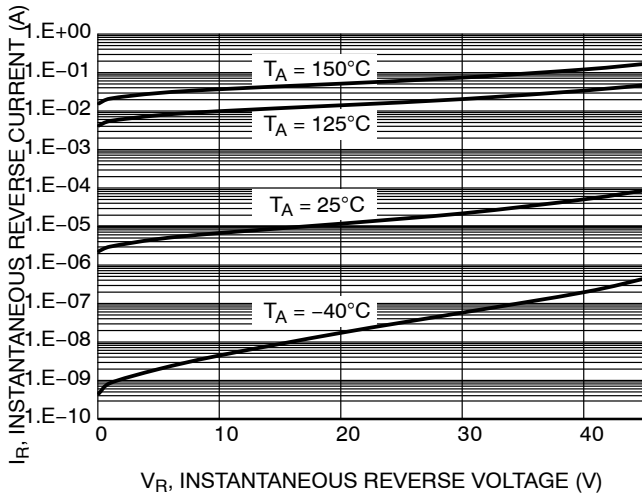


Figure 3. Typical Reverse Characteristics

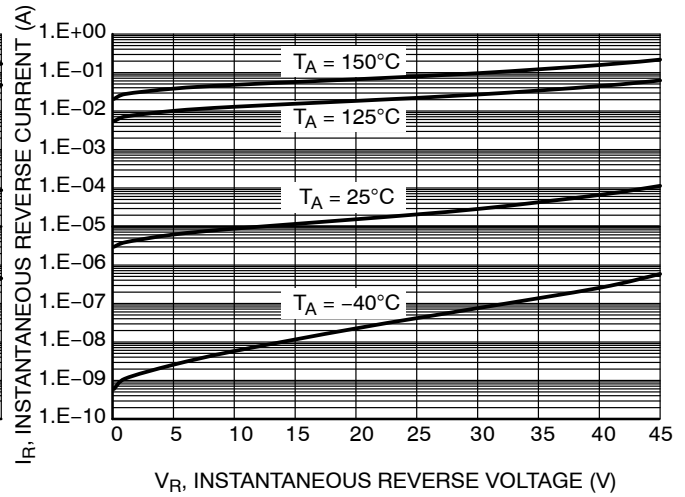


Figure 4. Maximum Reverse Characteristics

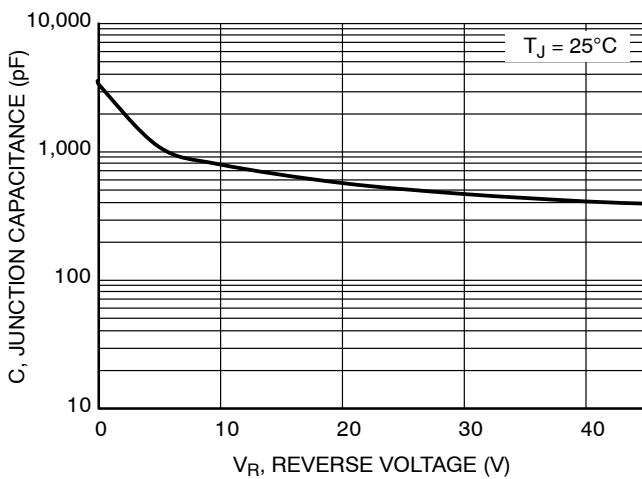


Figure 5. Typical Junction Capacitance

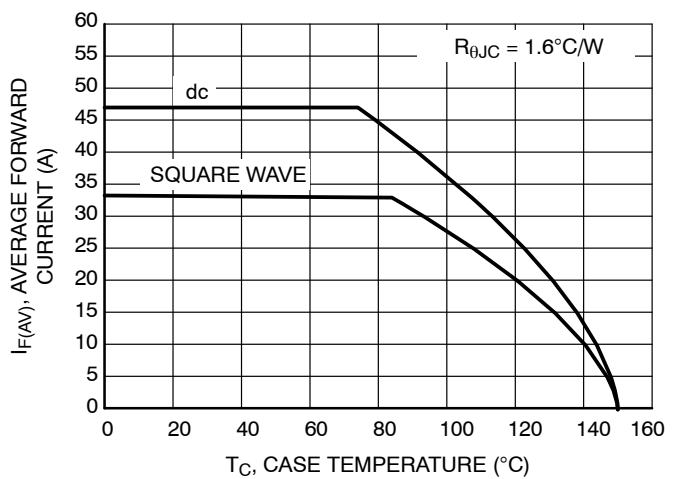


Figure 6. Current Derating

MBR2045EMFS, NRVB2045EMFS

TYPICAL CHARACTERISTICS (continued)

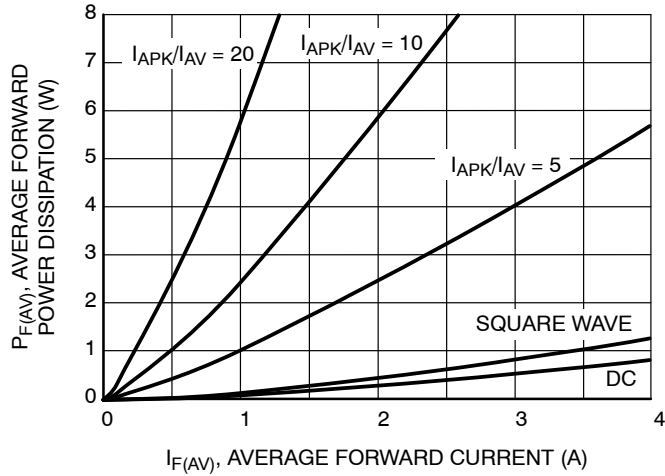


Figure 7. Forward Power Dissipation

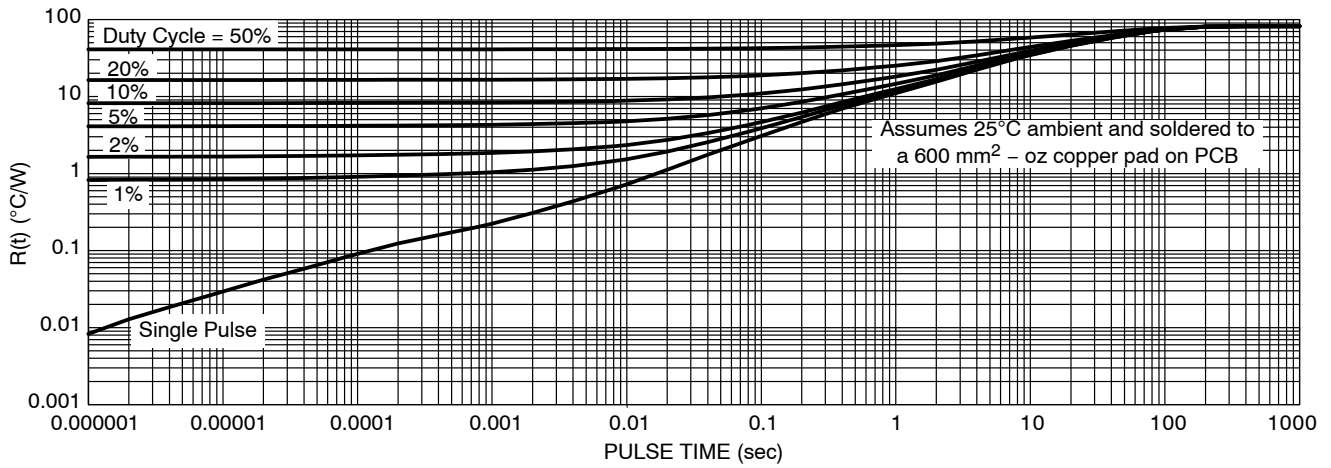
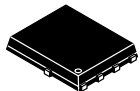


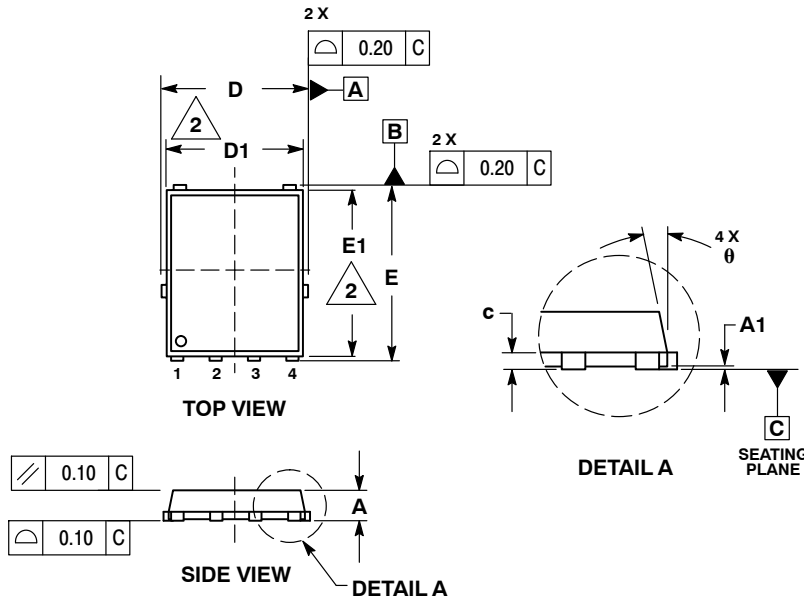
Figure 8. Thermal Response



1
SCALE 2:1

DFN5 5x6, 1.27P
(SO-8FL)
CASE 488AA
ISSUE N

DATE 25 JUN 2018

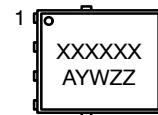


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION D1 AND E1 DO NOT INCLUDE MOLD FLASH PROTRUSIONS OR GATE BURRS.

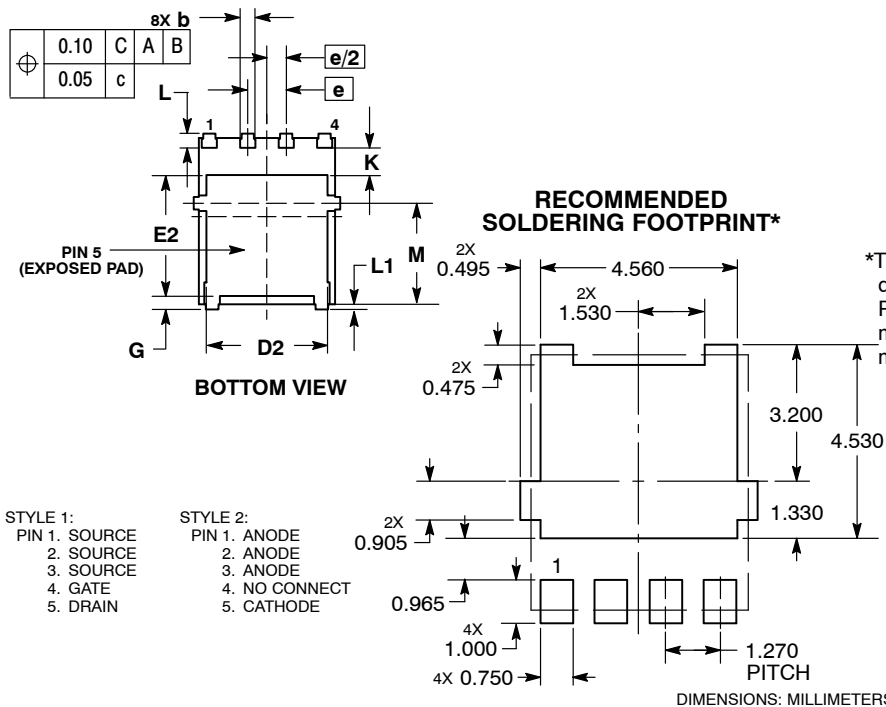
DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.90	1.00	1.10
A1	0.00	---	0.05
b	0.33	0.41	0.51
c	0.23	0.28	0.33
D	5.00	5.15	5.30
D1	4.70	4.90	5.10
D2	3.80	4.00	4.20
E	6.00	6.15	6.30
E1	5.70	5.90	6.10
E2	3.45	3.65	3.85
e	1.27 BSC		
G	0.51	0.575	0.71
K	1.20	1.35	1.50
L	0.51	0.575	0.71
L1	0.125 REF		
M	3.00	3.40	3.80
θ	0°	---	12°

GENERIC MARKING DIAGRAM*



- XXXXXX = Specific Device Code
- A = Assembly Location
- Y = Year
- W = Work Week
- ZZ = Lot Traceability

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



- STYLE 1:
1. SOURCE
 2. SOURCE
 3. SOURCE
 4. GATE
 5. DRAIN

- STYLE 2:
1. ANODE
 2. ANODE
 3. ANODE
 4. NO CONNECT
 5. CATHODE

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	DFN5 5x6, 1.27P (SO-8FL)	PAGE 1 OF 1

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